

# **Schottky Barrier Rectifier**

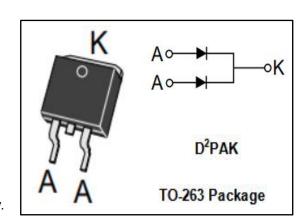
# STPS20150CG

#### **FEATURES**

- Multilayer Metal -Silicon Potential Structure.
- Low Leakage Current.
- · High Current Capability, High Efficiency.
- High Junction Temperature Capability.
- Minimum Lot-to-Lot variations for robust device performance and reliable operation.

### **MECHANICAL CHARACTERISTICS**

- · Low Voltage High Frequency Switching Power Supply.
- Low Voltage High Frequency Invers Circuit.
- Low Voltage Continued Circuit and Protection Circuit.



## ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

| SYMBOL   | PARAMETER  | VALUE    | UNIT         |
|--|--|----------|--------------|
| V <sub>RRM</sub><br>V <sub>RMS</sub><br>V <sub>R</sub> | Peak Repetitive Reverse Voltage<br>RMS Voltage<br>DC Blocking Voltage                              | 150      | V            |
| I <sub>F(AV)</sub>                                     | Average Rectified Forward Current (Per Leg) (Total)  | 10<br>20 | А            |
| I <sub>FSM</sub>                                       | Nonrepetitive Peak Surge Current 8.3ms single half sine-wave superimposed on rated load conditions | 180      | А            |
| P <sub>ARM</sub>                                       | Repetitive peak avalanche power tp=10us,Tj=125℃  | 480      | W            |
| TJ   | Junction Temperature   | -65~175  | $^{\circ}$ C |
| T <sub>stg</sub>                                       | Storage Temperature Range  | -65~175  | $^{\circ}$   |

### THERMAL CHARACTERISTICS

| SYMBOL              | PARAMETER                           | MAX | UNIT |
|---------------------|-------------------------------------|-----|------|
| R <sub>th j-c</sub> | Thermal Resistance,Junction to Case | 2.2 | °C/W |

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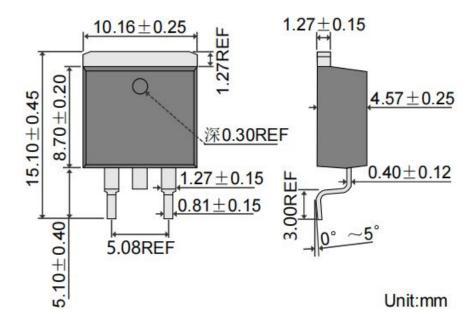


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### **ELECTRICAL CHARACTERISTICS**(Pulse Test: Pulse Width≤300 μ s,Duty Cycle≤1%)

| SYMBOL         | PARAMETER                             | CONDITIONS   | MAX        | UNIT |
|----------------|---------------------------------------|--|------------|------|
| VF             | Maximum Instantaneous Forward Voltage | I <sub>F</sub> = 10A; T <sub>C</sub> = 25°C<br>I <sub>F</sub> = 20A; T <sub>C</sub> = 25°C | 0.9<br>1.0 | V    |
| I <sub>R</sub> | Maximum Instantaneous Reverse Current | Rated DC Voltage, T <sub>C</sub> = 25°C  | 5.0        | uA   |



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